



STTH2003CT/CG/CF

HIGH FREQUENCY SECONDARY RECTIFIER

MAJOR PRODUCT CHARACTERISTICS

$I_{F(AV)}$	2 x 10 A
V_{RRM}	300 V
$T_j(\text{max})$	175 °C
$V_F(\text{max})$	1 V
$t_{rr}(\text{max})$	35 ns

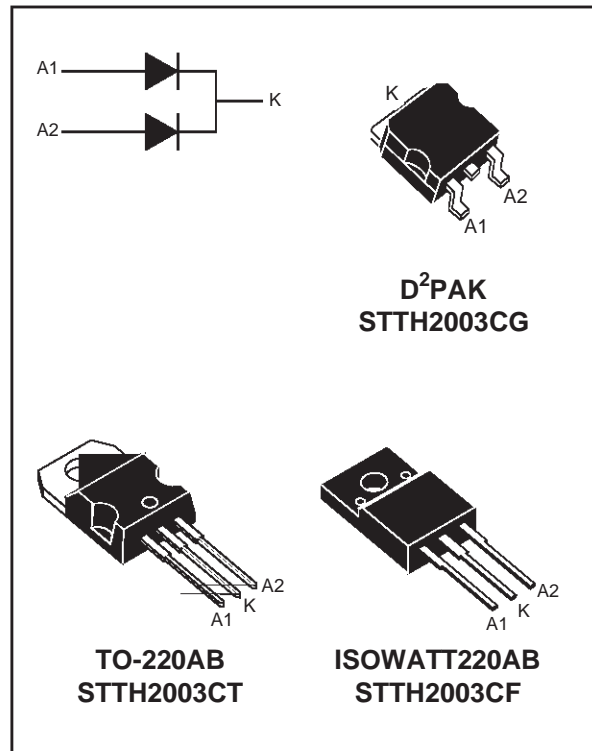
FEATURES AND BENEFITS

- COMBINES HIGHEST RECOVERY AND REVERSE VOLTAGE PERFORMANCE
- ULTRA-FAST, SOFT AND NOISE-FREE RECOVERY

DESCRIPTION

Dual center tap Fast Recovery Epitaxial Diodes suited for Switch Mode Power Supply and high frequency DC/DC converters.

Packaged in TO-220AB, ISOWATT220AB or D²PAK, this device is especially intended for secondary rectification.



ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter			Value	Unit	
V_{RRM}	Repetitive peak reverse voltage			300	V	
$I_{F(RMS)}$	RMS forward current			30	A	
$I_{F(AV)}$	Average forward current $\delta = 0.5$	TO-220AB / D ² PAK	$T_c = 140^\circ\text{C}$	Per diode Per device	10 20	A
		ISOWATT220AB	$T_c = 125^\circ\text{C}$			
I_{FSM}	Surge non repetitive forward current		$t_p = 10 \text{ ms}$ sinusoidal	110	A	
I_{RSM}	Non repetitive avalanche current		$t_p = 20 \mu\text{s}$ square	5	A	
T_{stg}	Storage temperature range			-65 + 175	°C	
T_j	Maximum operating junction temperature			175	°C	

THERMAL RESISTANCES

Symbol	Parameter			Value	Unit
$R_{th(j-c)}$	Junction to case	TO-220AB/ D ² PAK	Per diode	2.5	°C/W
			Total	1.3	
		ISOWATT220AB	Per diode	3.9	
			Total	3.2	
$R_{th(c)}$		TO-220AB/ D ² PAK	Coupling	0.1	
		ISOWATT220AB	Coupling	2.5	

STATIC ELECTRICAL CHARACTERISTICS (per diode)

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
I_R^*	Reverse leakage current	$V_R = 300\text{ V}$	$T_j = 25^\circ\text{C}$			20	μA
			$T_j = 125^\circ\text{C}$		30	300	
V_F^{**}	Forward voltage drop	$I_F = 10\text{ A}$	$T_j = 25^\circ\text{C}$			1.25	V
			$T_j = 125^\circ\text{C}$		0.85	1	

Pulse test : * $t_p = 5\text{ ms}$, $\delta < 2\%$

** $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation :

$$P = 0.75 \times I_{F(AV)} + 0.025 I_{F(RMS)}^2$$

RECOVERY CHARACTERISTICS

Symbol	Tests conditions			Min.	Typ.	Max.	Unit
trr	$I_F = 0.5\text{ A}$	$I_{rr} = 0.25\text{ A}$	$I_R = 1\text{ A}$	$T_j = 25^\circ\text{C}$		25	ns
	$I_F = 1\text{ A}$	$di_F/dt = -50\text{ A}/\mu\text{s}$	$V_R = 30\text{ V}$			35	
tfr	$I_F = 10\text{ A}$	$di_F/dt = 100\text{ A}/\mu\text{s}$		$T_j = 25^\circ\text{C}$		230	ns
V_{FP}	$V_{FR} = 1.1 \times V_F\text{ max.}$						3.5
S_{factor}	$V_{CC} = 200\text{ V}$	$I_F = 10\text{ A}$		$T_j = 125^\circ\text{C}$	0.3		-
I_{RM}	$di_F/dt = 200\text{ A}/\mu\text{s}$						8

Fig. 1: Conduction losses versus average current (per diode).

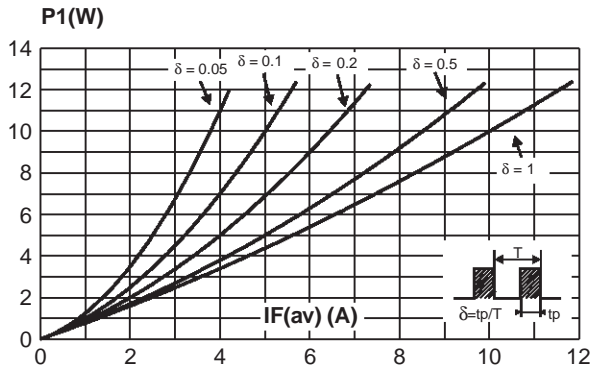


Fig. 2: Forward voltage drop versus forward current (maximum values, per diode).

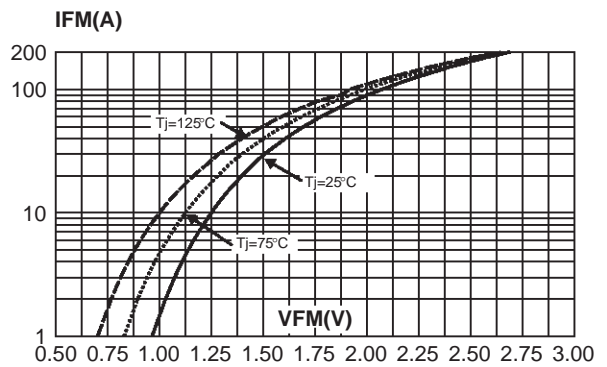


Fig. 3-1: Relative variation of thermal impedance junction to case versus pulse duration (TO-220AB / D²PAK).

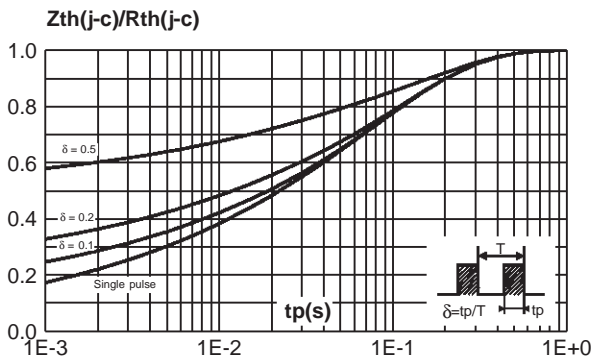


Fig. 3-2: Relative variation of thermal impedance junction to case versus pulse duration (ISOWATT220AB).

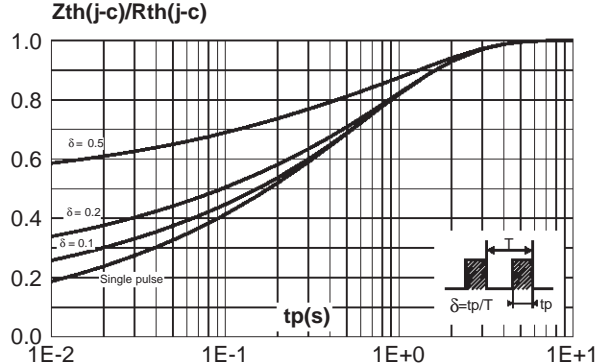


Fig. 4: Peak reverse recovery current versus dI_F/dt (90% confidence, per diode).

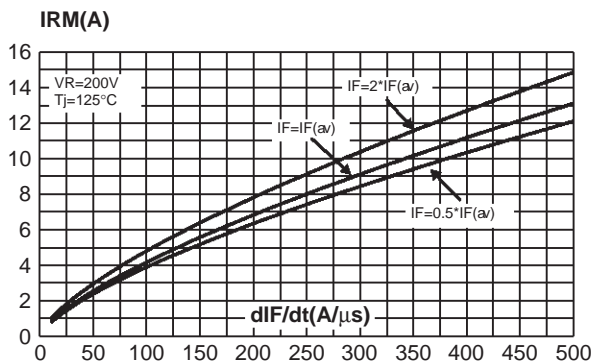


Fig. 5: Reverse recovery time versus dI_F/dt (90% confidence, per diode).

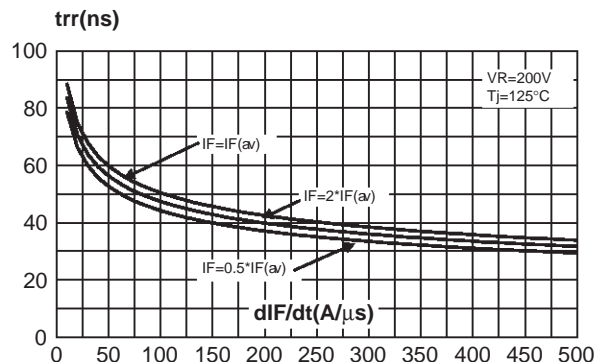


Fig. 6: Softness factor (t_b/t_a) versus dI_F/dt (typical values, per diode).

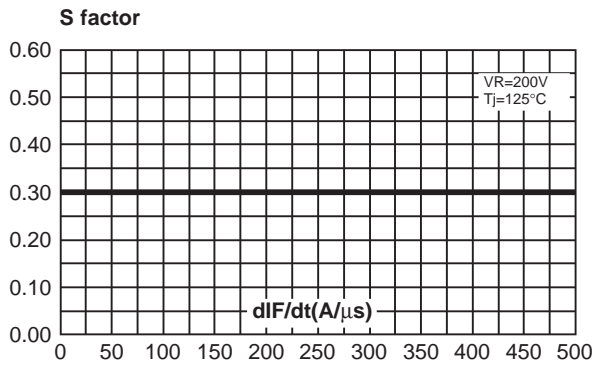


Fig. 8: Transient peak forward voltage versus dI_F/dt (90% confidence, per diode) (TO-220AB).

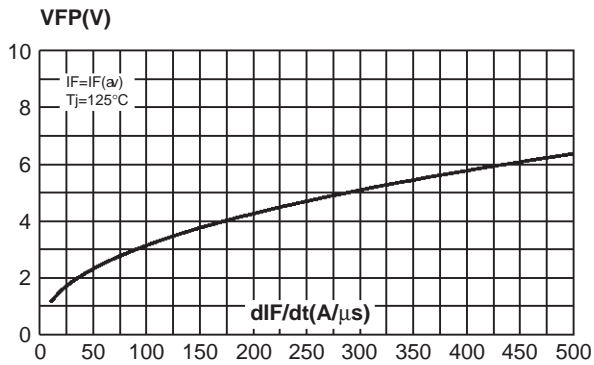


Fig. 10: Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness: $35\mu m$) (D^2PAK)

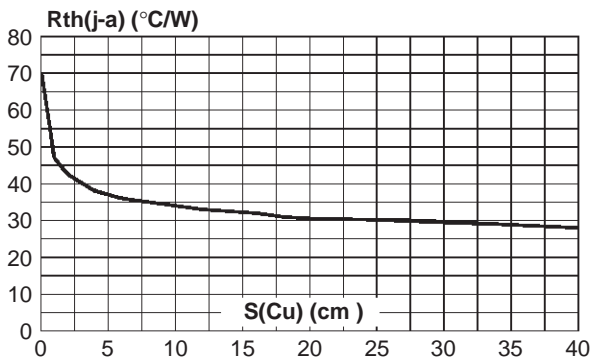


Fig. 7: Relative variation of dynamic parameters versus junction temperature (reference: $T_j = 125^\circ C$).

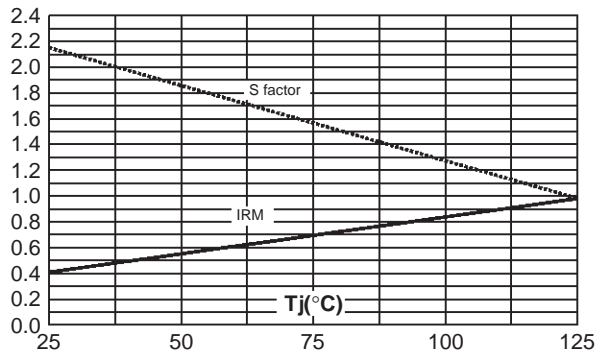
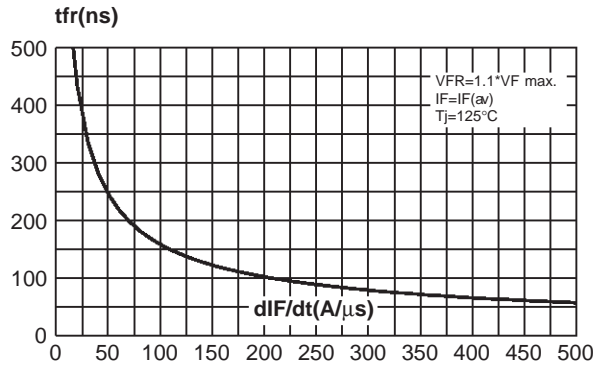
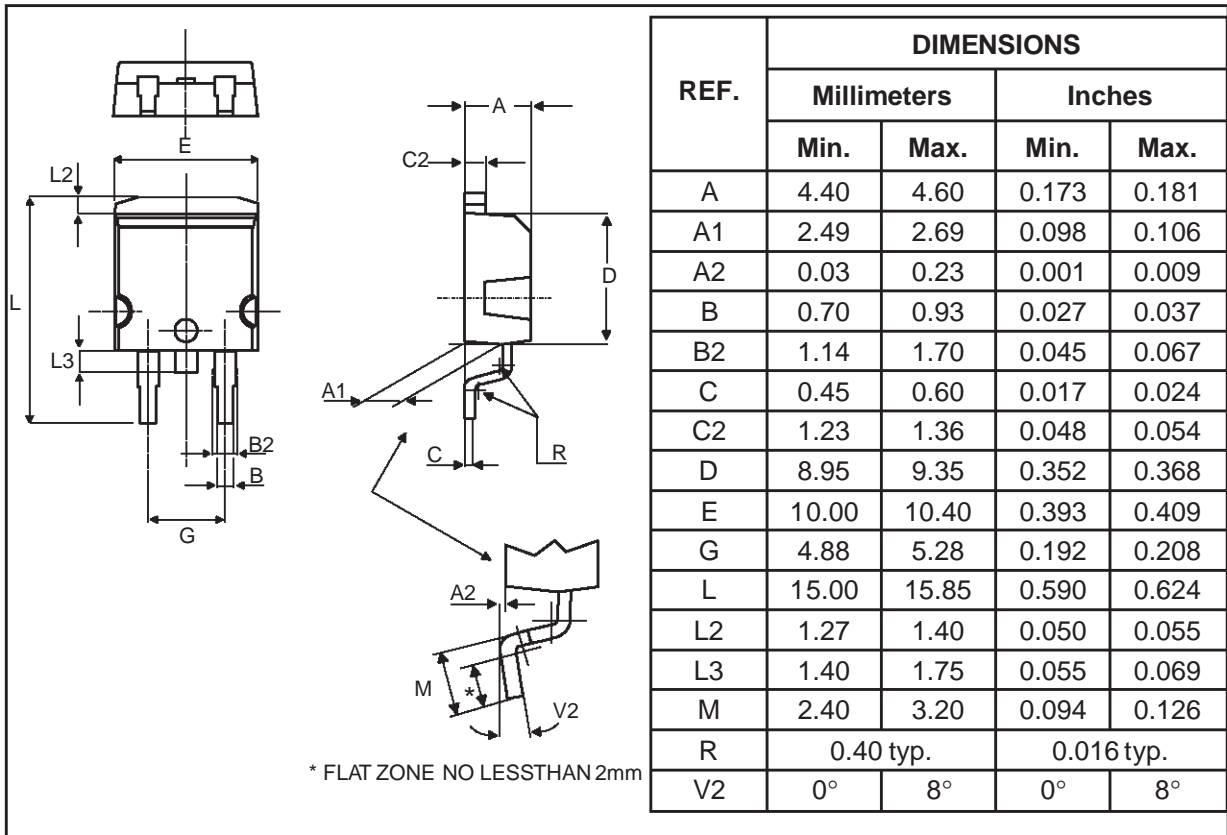


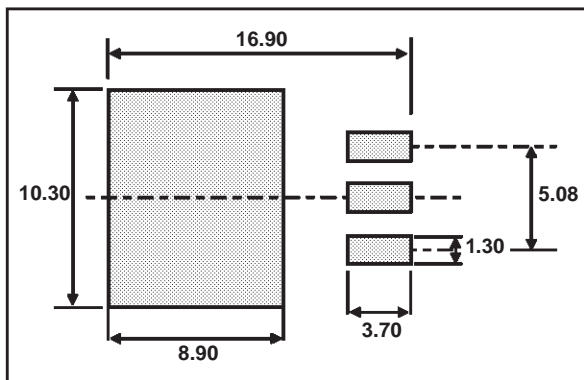
Fig. 9: Forward recovery time versus dI_F/dt (90% confidence, per diode).



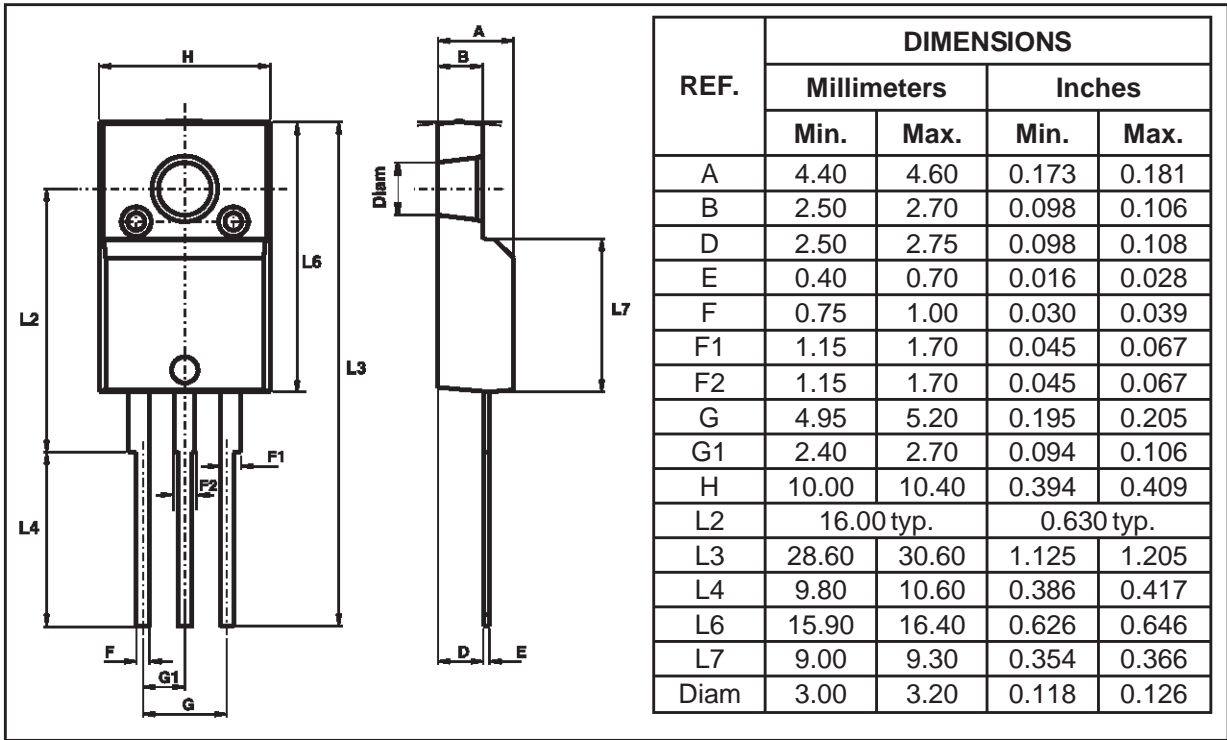
PACKAGE MECHANICAL DATA
D²PAK

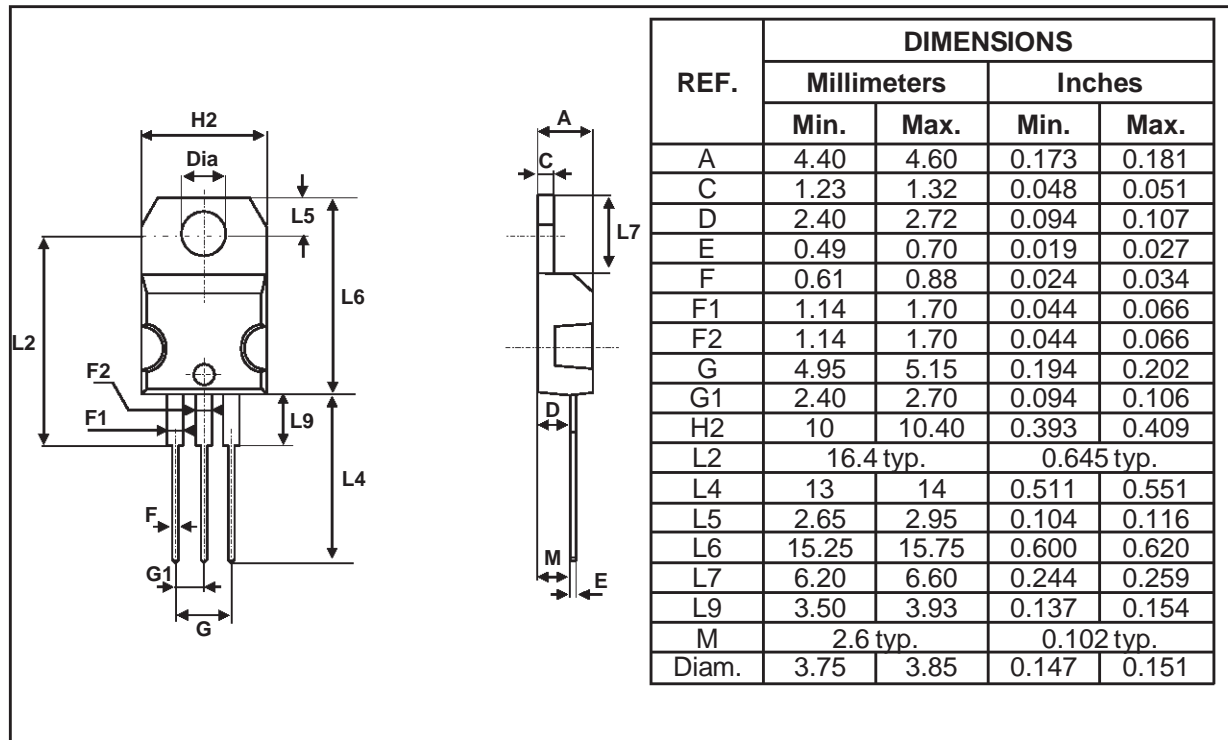


FOOT PRINT DIMENSIONS (in millimeters)
D²PAK



PACKAGE MECHANICAL DATA
ISOWATT220AB



PACKAGE MECHANICAL DATA
 TO-220AB


Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH2003CT	STTH2003CT	TO-220AB	2.2 g.	50	Tube
STTH2003CG	STTH2003CG	D ² PAK	1.48 g.	50	Tube
STTH2003CG-TR	STTH2003CG	D2PAK	1.48 g.	500	Tape & reel
STTH2003CF	STTH2003CF	ISOWATT220AB	2.08 g.	50	Tube

- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N.m.
- Maximum torque value: 0.70 N.m.
- Epoxy meets UL 94,V0

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